

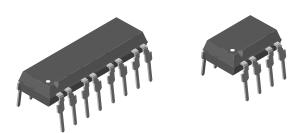
## K827PH, K847PH

RoHS

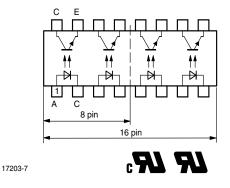
COMPLIANT

Vishay Semiconductors

## **Optocoupler, Phototransistor Output**



17203-6



### LINKS TO ADDITIONAL RESOURCES



### DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

#### FEATURES

- DC isolation test voltage 5000 V<sub>RMS</sub>
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



- Programmable logic controllers
- Modems
- Answering machines
- General applications

#### **AGENCY APPROVALS**

- <u>UL</u>
- <u>cUL</u>
- **ORDERING INFORMATION** 8 # 7 Ρ н κ DIP-8 / DIP-16 PART NUMBER 7.62 mm **AGENCY CERTIFIED / PACKAGE** CTR (%) UL, cUL 50 to 600 DIP-8 K827PH DIP-16 K847PH

Note

• K827PH and K847PH are marked as K827P and K847P respectively



# K827PH, K847PH

### **Vishay Semiconductors**

ABSOLUTE MAXIMUM RATIN	<b>GS</b> (T <sub>amb</sub> = 25 °C, unless ot	nerwise specifie	d)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT		· ·		•
Reverse voltage		V <sub>R</sub>	6	V
Forward current		I <sub>F</sub>	60	mA
Forward surge current	t <sub>P</sub> ≤ 10 µs	I <sub>FSM</sub>	1.5	A
Power dissipation		P <sub>diss</sub>	100	mW
Junction temperature		Tj	125	°C
OUTPUT		· · ·		<u>.</u>
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		IC	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation		P <sub>diss</sub>	150	mW
Junction temperature		Tj	125	°C
COUPLER				
Total power dissipation		P <sub>tot</sub>	250	mW
Operating ambient temperature range		T <sub>amb</sub>	-40 to +100	°C
Storage temperature range		T <sub>stg</sub>	-55 to +125	°C
Soldering temperature <sup>(1)</sup>	2 mm from case, t $\leq$ 10 s	T <sub>sld</sub>	260	°C

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to wave profile for soldering conditions for through hole devices

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	1.25	1.6	V	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz$	Cj	-	50	-	pF	
OUTPUT							
Collector emitter voltage	I <sub>C</sub> = 100 μA	V <sub>CEO</sub>	70	-	-	V	
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7	-	-	V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>	-	-	100	nA	
COUPLER							
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	V <sub>CEsat</sub>	-	-	0.3	V	
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}, R_L = 100 \Omega$	f <sub>c</sub>	-	100	-	kHz	
Coupling capacitance	f = 1 MHz	C <sub>k</sub>	-	0.3	-	pF	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX.						UNIT	
I <sub>C</sub> /I <sub>F</sub>	$V_{CE} = 5 V, I_F = 5 mA$	K827PH	CTR	50	-	600	%
		K847PH	CTR	50	-	600	%

Rev. 1.2, 11-Jan-2024

2

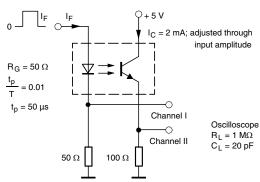
Document Number: 81135



# K827PH, K847PH

### Vishay Semiconductors

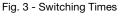
SWITCHING CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega \\ (see \ figure \ 1) \end{array}$	t <sub>d</sub>	-	3	-	μs
Rise time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$	t <sub>r</sub>	-	3	-	μs
Fall time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$	t <sub>f</sub>	-	4.7	-	μs
Storage time	$\label{eq:VS} \begin{array}{l} V_S = 5 \mbox{ V, } I_C = 2 \mbox{ mA, } R_L = 100 \ \Omega \\ \mbox{(see figure 1)} \end{array}$	ts	-	0.3	-	μs
Turn-on time	$\label{eq:VS} \begin{array}{l} V_S = 5 \text{ V}, \text{ I}_C = 2 \text{ mA}, \text{ R}_L = 100 \ \Omega \\ \text{(see figure 1)} \end{array}$	t <sub>on</sub>	-	6	-	μs
Turn-off time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$	t <sub>off</sub>	-	5	-	μs
Turn-on time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 $k\Omega$ (see figure 2)	t <sub>on</sub>	-	9	-	μs
Turn-off time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ (see figure 2)	t <sub>off</sub>	-	18	-	μs



 $\mathbf{I}_{\mathsf{F}}$ 0 t<sub>p</sub> t  $\mathsf{I}_\mathsf{C}$ 100 % 90 % 10 % 0 t tf t<sub>off</sub>  $egin{aligned} t_{p} \ t_{d} \ t_{r} \ t_{on} \ (= t_{d} + t_{r}) \end{aligned}$ Pulse duration Storage time ts Delay time Rise time Turn-on time Fall time Turn-off time t  $t_{off} (= t_s + t_f)$ 96 11698

95 10804

Fig. 1 - Test Circuit, Non-Saturated Operation



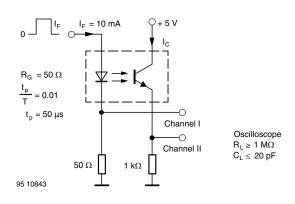


Fig. 2 - Test Circuit, Saturated Operation

3



# K827PH, K847PH

### **Vishay Semiconductors**

SAFETY AND INSULATION RATINGS	i			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		40 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>
Maximum transient isolation voltage		V <sub>IOTM</sub>	10 000	V <sub>peak</sub>
Maximum repetitive peak isolation voltage		V <sub>IORM</sub>	890	V <sub>peak</sub>
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	400	mW
Input safety current		I <sub>SI</sub>	275	mA
Safety temperature		T <sub>S</sub>	175	°C
Creepage distance			≥7	mm
Clearance distance			≥7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

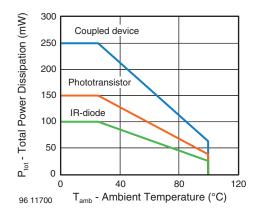


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

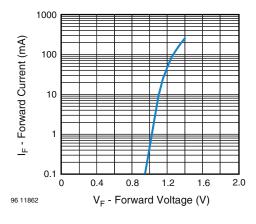


Fig. 5 - Forward Current vs. Forward Voltage

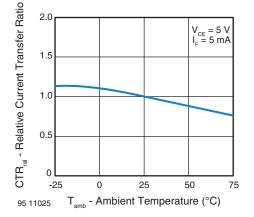


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

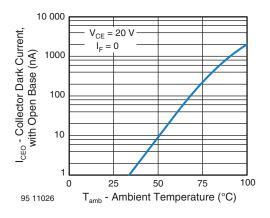


Fig. 7 - Collector Dark Current vs. Ambient Temperature

Rev. 1.2, 11-Jan-2024

4 For technical questions, contact: <u>optocoupleranswers@v</u>

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000





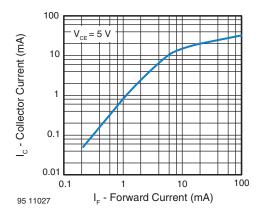


Fig. 8 - Collector Current vs. Forward Current

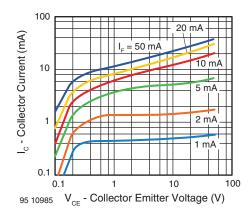


Fig. 9 - Collector Current vs. Collector Emitter Voltage

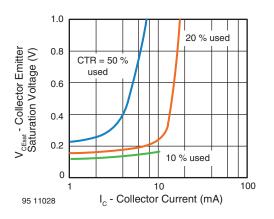


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

# K827PH, K847PH

### **Vishay Semiconductors**

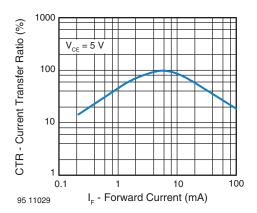


Fig. 11 - Current Transfer Ratio vs. Forward Current

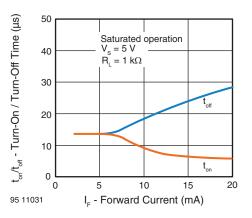


Fig. 12 - Turn-On / Turn-Off Time vs. Forward Current

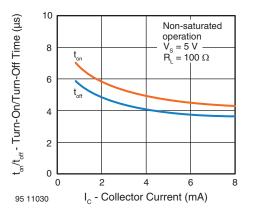
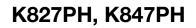


Fig. 13 - Turn-On / Turn-Off Time vs. Collector Current

Rev. 1.2, 11-Jan-2024

Document Number: 81135

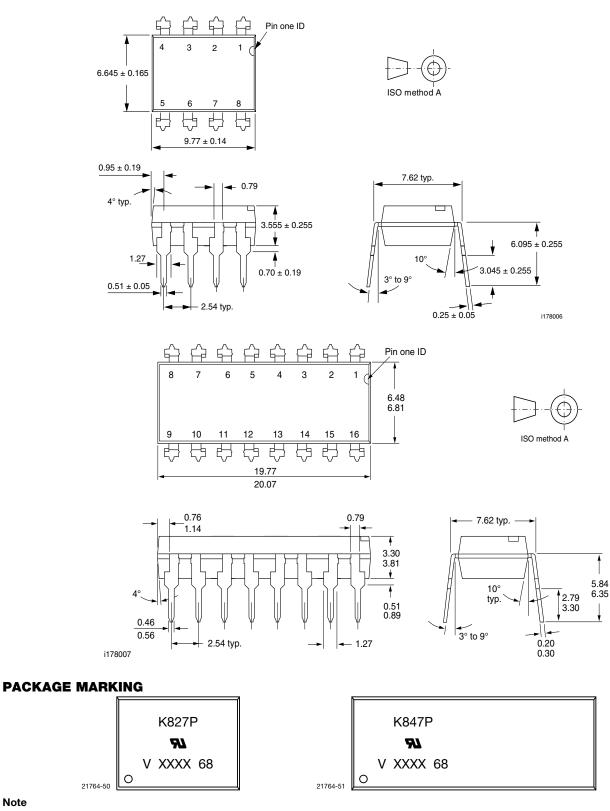
For technical questions, contact: optocoupleranswers@ THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



**Vishay Semiconductors** 

### **PACKAGE DIMENSIONS** in millimeters

VISHAY



Note

XXXX = LMC (lot marking code)

Rev. 1.2, 11-Jan-2024

6

Document Number: 81135

For technical questions, contact: optocoupleranswers@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <a href="http://www.vishay.com/doc?91000">www.vishay.com/doc?91000</a>



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2024